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What is claimed is:

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1. An active-matrix addressed reflective LCD (liquid crystal display), which comprises:

a first substrate (74) which is transparent, a second substrate (56), a lower insulation film (60) formed on said second substrate, a plurality of switching elements (84) respectively provided for each pixel, an insulation layer (66, 68) having a surface irregularly configured, and a reflection film (70) formed on said insulation film and having an irregularly configured surface depending on the irregular surface of said insulation film; and a liquid crystal layer provided between said first substrate and said reflection film, characterized by

an upper electrode (62) being provided for each pixel and located in a region wherein said reflection film is provided, said upper electrode being electrically coupled to a source electrode of the switching element; and

a lower electrode (58) provided between said second substrate and said lower insulation film, said lower electrode forming a storage capacitance with said upper electrode.

- 2. The active-matrix addressed reflective LCD as claimed in claim 1, wherein the irregularly configured surface of said insulation film comprises a plurality of substantially linear projections, and a plurality of recesses surrounded by the linear projections.
- 3. The active-matrix addressed reflective LCD as claimed in claim 1 or 2, wherein the switching element of a given pixel is a thin film transistor whose gate electrode is coupled to a gate line, and said lower insulation layer functions as a gate insulation layer, and wherein said lower electrode is coupled to a gate line assigned to a pixel adjacent to said given pixel.

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- 4. The active-matrix addressed reflective LCD as claimed in any of claims 1 or 3, wherein said lower insulation film has no step on the surface thereof in a region wherein said reflection film is provided.
- 5. The active-matrix addressed reflective LCD as claimed in any of claims 1 to 3, wherein said insulation layer comprises a first layer patterned by lithography so as to have the irregular configuration on the surface thereof, and a second layer formed on said first layer such as to imitate the irregular surface of said first layer.
- 6. The active-matrix addressed reflective LCD as claimed in any of claims 1 to 4, wherein said reflection film is electrically coupled to said upper electrode or said source electrode via a contact hole provided in said insulation layer.
- 7. The active-matrix addressed reflective LCD as claimed in any of claims 1 to
 4, wherein said source electrode is electrically coupled to said reflection film.
 - 8. A method of fabricating an active-matrix addressed reflective LCD, comprising the steps of:
 - (a) forming a reflection layer (62) on a substrate (56);
- (b) forming an insulation layer (66) on said reflection layer, after which said insulation layer is patterned by exposure so as to provide irregularity on the surface of said insulation layer; and
- (c) forming a reflection film (70) on said insulation film,
 wherein said insulation layer is patterned with assist of light reflected by said
 reflection layer.
 - 9. The method as claimed in claim 8, wherein said reflection layer (62) is formed such that the surface thereof is flattened.

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- 10. The method as claimed in claim 8 or 9, wherein said reflection layer (62) is used as one of two electrodes of a storage capacitor developed in each pixel of said reflective LCD.
- 5 11. The method as claimed in any of claims 8 to 10, wherein the step (b) comprises:

patterning a first photoresist layer by exposure so as to form a predetermined irregularity on a surface of said first photoresist layer; and

forming a second photoresist layer on the patterned first photoresist layer, thereby forming irregularity on a surface of said second photoresist layer.

12. The method as claimed in any of claims 8 to 11, wherein the step (b) comprises:

exposing a photoresist layer using at low intensity of exposing light so as to

form a predetermined irregularity on said photoresist layer; and

exposing said photoresist layer at high intensity of exposing light so as to form
a contact hole.